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Structural, magnetic and magneto-transport properties of Ptalloyed MnBi thin films

Parashu Kharel University of Nebraska-Lincoln, pkharel2@unl.edu

Ralph Skomski University of Nebraska-Lincoln, rskomski2@unl.edu

Roger D. Kirby University of Nebraska-Lincoln, rkirby1@unl.edu

David J. Sellmyer University of Nebraska-Lincoln, dsellmyer@unl.edu

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[Structural, magnetic and magneto-transport properties of Pt-alloyed MnBi](http://dx.doi.org/10.1063/1.3360204) [thin films](http://dx.doi.org/10.1063/1.3360204)

P. Kharel,^{a)} Ralph Skomski, R. D. Kirby, and D. J. Sellmyer

Department of Physics and Astronomy, Nebraska Center for Materials and Nanoscience, University of Nebraska, Lincoln, Nebraska, 68588, USA

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The structural, magnetic and magneto-transport properties of highly c-axis oriented Mn55−*x*Pt*x*Bi45 $(x=0, 1.5, 3,$ and 4.5) thin films have been investigated. The coercivity of the Pt-alloyed thin films increases and the saturation magnetization decreases as the Pt concentration increases. The anisotropy field *Ho* increases as a function of Pt concentration, too but the coercivity increases more rapidly than the anisotropy field. This indicates an enhanced domain-wall pinning, caused by increased interstitial disorder due to the occupancy of regular Mn sites by Pt. The same mechanism explains the reduced magnetization. All samples exhibit a large extraordinary Hall effect with anomalous Hall coefficient about an order of magnitude larger than the ordinary Hall coefficient. © *2010 American Institute of Physics*. doi[:10.1063/1.3360204](http://dx.doi.org/10.1063/1.3360204)

I. INTRODUCTION

There has been considerable interest in understanding the magnetic, optical, and magneto-transport properties of MnBi-based materials because of their substantial magneto-optical and permanent magnet properties.^{[1](#page-3-0)} MnBi exhibits interesting properties including an extraordinarily large Kerr rotation, $\frac{2}{3}$ $\frac{2}{3}$ $\frac{2}{3}$ $\frac{2}{3}$ $\frac{2}{3}$ a Curie temperature well above room temperature, $\frac{3}{3}$ a high coercivity with a rectangular hysteresis loop, 4 and a large perpendicular anisotropy in thin films at room temperature.³

Pure MnBi adopts the hexagonal NiAs-type crystal structure at room temperature with lattice constants of *a* $=4.29$ Å and $c=6.12$ Å.⁶ Around 628 K, it undergoes coupled structural and magnetic phase transitions from a ferromagnetic low-temperature phase (LTP) to a paramagnetic high-temperature phase (HTP).^{[4](#page-3-3)} If MnBi in the HTP is rapidly quenched, a ferromagnetic quenched HTP (QHTP) with a Curie temperature of about 440 K is obtained.^{[7](#page-3-6)} QHTP is thermally unstable and transforms slowly back to LTP at room temperature with a time constant of about two years.^{[8](#page-3-7)} In addition to the structural instability, MnBi in LTP shows an increasing coercivity as temperature increases reaching a maximum at 553 K. $⁴$ These circumstances have led to several</sup> studies of the effect of dopants on the various properties of this material. $9-14$ $9-14$ Some of these experiments show that the structural, magnetic, and magneto-optical properties of MnBi can be controlled by doping it with a third element. The goal of this study is to understand and control the structural, magnetic, and magneto-transport properties of MnBi-based alloys by alloying with the heavy and noble element Pt.

II. EXPERIMENTAL METHODS

We have synthesized Pt-alloyed MnBi thin films having post-annealed stoichiometry of Mn_{55−*x*}Pt_{*x*}Bi₄₅ (*x*=0, 1.5, 3, and 4.5) by sequential evaporation of Bi, Mn, and Pt onto a glass substrate at room temperature using an AJA e-beam evaporation system. The base pressure of the evaporation chamber was 4×10^{-9} Torr. Bi and Mn were evaporated from alumina crucibles and Pt was evaporated from a graphite crucible. The atomic ratios of the constituent elements in the $Mn_{55-x}Pt_xBi_{45}$ films were estimated from the respective layer thicknesses and were later confirmed using energy dispersive x-ray (EDX) spectroscopy. The deposition layer thickness was controlled by a quartz crystal thickness monitor. All the samples were annealed *in situ* immediately after deposition at a temperature of 375 °C for one hour. The thicknesses of the postannealed samples were determined from x-ray reflection measurement using a Bruker X-ray diffractometer, and for the structural characterization of the thin films a Rigaku X-ray diffractometer was used. Magnetic properties were investigated using Quantum Design magnetic property measurement system (MPMS) and magnetotransport properties were studied using Keithley electrometers in conjunction with MPMS.

III. RESULTS AND DISCUSSION

Figure [1](#page-1-0) shows the x-ray diffraction (XRD) patterns of $Mn_{55-x}Pt_xBi_{45}$ ($x=0$ and 4.5) thin films collected at room

FIG. 1. (Color online) XRD patterns of Mn_{55−*x*}Pt_{*x*}Bi₄₅ thin films indexed to hexagonal NiAs-type structure. Inset (i) shows the x-ray reflectivity oscillations for samples with 0 at. $%$ and 4.5 at. $%$ platinum and inset (ii) shows the change in the c-axis lattice constant with platinum concentration.

a)Electronic mail: pkharel2@unl.edu.

FIG. 2. (Color online) Magnetization as a function of magnetic field for Mn_{55-*x*}Pt_xBi₄₅ thin films. Inset (right): Change in the saturation magnetization M_s and the coercivity H_c of the samples with Pt concentration. Inset (left): Temperature dependence of the magnetization for $Mn_{50.5}Pt_{4.5}Bi_{45}$ thin film measured in two perpendicular directions.

temperature. The diffraction peaks in the XRD patterns can be indexed to the hexagonal MnBi crystal structure with space group P63/mmc, although a small trace of unannealed bismuth has been detected. The presence of only the MnBi (002) and (004) reflections indicates that the films are highly c-axis oriented. We have noticed that the intensity of MnBi (002) peak decreases and Bi (012) peak increases with the increase in Pt concentration. This indicates that the substitution of Pt into MnBi lattice may cause structural disorder. The estimated values of c-axis lattice parameter from the position of the most intense (002) peak are very close to the value $(c=6.12 \text{ Å})$ reported for the LTP MnBi. This suggests that the samples have adopted the LTP of MnBi. As shown in the inset (ii) of Fig. [1,](#page-1-0) there is a small increase in c with the increase in Pt concentration, which is consistent with the incorporation of Pt in the octahedral site (Mn site) of MnBi lattice.

Thin film quality can also be assessed from the nature of the top and bottom interfaces of the thin film. Pt substitution has increased the roughness of the interfaces. The faster damping of x-ray reflectivity oscillations in the Pt alloyed samples, as shown in the inset (i) of Fig. [1,](#page-1-0) is a consequence of the rough interfaces. The change in the surface morphology due to Pt substitution can be clearly seen in the atomic force microscope micrographs as well. The surface of $Mn_{55}Bi_{45}$ film is continuous with root-mean-square (rms) roughness of 1.7 nm over a 4×4 μ m² scan area and that of Mn_{50} , Pt_4 , Bi_{45} film is not continuous and have increased rms roughness of 2.6 nm over the same scan area (Figure not shown).

Figure [2](#page-2-0) shows the magnetization M as a function of magnetic field H for $Mn_{55-x}Pt_xBi_{45}$ ($x=0, 1.5, 3,$ and 4.5) thin films. M(H) curves were recorded at room temperature with magnetic field perpendicular to the plane of the samples. We have found that the saturation magnetizations (M_s) of Mn_{55−*x*}Pt_{*x*}Bi₄₅ films decrease monotonically with the increase in Pt concentration but the coercivities (H_c) increase as the Pt concentration increases. As shown in the right inset of Fig. [2,](#page-2-0) M_s decreases from 551 to 327 emu/cm³ and H_c increases from 4.7 to 12.5 kOe as Pt concentration increases from 0 to 4.5 at. %, although most of the change occurs between 1.5 and 4.5 at. %. Furthermore, the coercivities of

FIG. 3. (Color online) Magnetization as a function of magnetic field for Mn50.5Pt4.5Bi45 thin film measured in two perpendicular directions-*H* parallel to the sample plane $(H \perp c$ -axis) and *H* perpendicular to the sample plane $(H \| c$ -axis). Inset shows the change in anisotropy constant K_1 with platinum concentration.

all the $Mn_{55-x}Pt_xBi_{45}$ thin films decrease with the decrease in temperature, indicating that the samples are LTP even after Pt substitution. It has been found that the out-of-plane magnetization measured at 1 kOe of the samples shows a gradual decrease and in-plane magnetization shows a gradual increase as the temperature decreases below 200 K. However, this feature disappears when the $M(T)$ measurement is done above 10 kOe. This is attributed to the gradual deviation in magnetic moment from the c-axis which finally flips into the a-b plane. A representative $M(T)$ plot for the sample with 4.5% Pt is shown in the left inset of Fig. [2.](#page-2-0)

In order to determine the uniaxial anisotropy constants K_1 and K_2 , we have recorded M (H) loops both in the parallel and perpendicular directions. Representative M(H) loops for $Mn_{50.5}Pt_{4.5}Bi_{45}$ thin film are shown in Fig. [3.](#page-2-1) The samples maintain their large perpendicular anisotropy but platinum substitution significantly lowers the values of K_1 . We have determined the values of anisotropy constants for these samples using $E = K_1 \sin^2 \theta + K_2 \sin^4 \theta - H M_s \sin \theta$ and the Sucksmith–Thompson method, 15 where E is the energy density, K_1 and K_2 are the anisotropy constants, M_s is the saturation magnetization, and θ is the angle between easy axis and magnetization. As shown in the inset of Fig. $3, K_1$ $3, K_1$ decreases from 7.03×10^6 ergs/cm³ for Mn₅₅Bi₄₅ thin films to 5.60×10^6 ergs/cm³ for Mn_{50.5}Pt_{4.5}Bi₄₅ films.

As explained in the introduction, the phase structure of MnBi is very complicated, even in the bulk. However, a key feature of the system is the presence of large bipyramidal interstices in the NiAs structure, which can easily be occu-pied by the Mn atoms. As pointed out by Roberts,^{[16](#page-3-11)} each of these interstitial atoms is coordinated by five Mn atoms so that a single Mn atom with antiferromagnetic coupling yields a substantial reduction in the moment. Such a reduction is very likely because Mn and most Mn compounds exhibits a pronounced trend toward antiferromagnetism (AFM). AFM is generally favored for half-filled shells because the energy of electron in a filled 3*d*↑ subband is equal to the on-site energy, whereas the antiferromagnetic state can reduce its energy by interatomic hopping.¹⁷ Ordered MnBi is an exception, with a atomic structure and a charge state (essentially Mn^{3+}) supporting ferromagnetism. In the present system, the Mn-rich regions around the interstices are closer to antifer-

FIG. 4. (Color online) Magnetization *M* and Hall resistivity ρ_{xy} as a function of magnetic field for $Mn_{53.5}Pt_{1.5}Bi_{45}$ thin film. Inset (right) shows the change in the ordinary Hall coefficient (R_0) and extraordinary Hall coefficient (R_s) with platinum concentration. Inset (left): Hall resistivity as a function of magnetic field for $Mn_{50.5}Pt_{4.5}Bi_{45}$ film.

romagnetic bulk Mn. The excess Mn pushes the system toward antiferromagnetic (or noncollinear) order, and the Pt atoms further increase the interstitial Mn occupancy by displacing the Mn atoms from their regular sites. The effect is further enhanced by the Pt atoms on the regular lattice sites, which further dilute and probably reverse the FM interactions of MnBi.

The coercivity scales as $H_o = 2K_1/M_s$ but it also exhibits a strong dependence on the defect structure¹⁸ and some dependence on K_2 .^{[19](#page-3-14)} Since K_2 does not change very much, from 2.5×10^6 ergs/cm³ for $Mn_{55}Bi_{45}$ to 2.06 $\times 10^6$ ergs/cm³ for the sample with 4.5% Pt, we ignore the effect of K_2 on the coercivity. The K_1 -only anisotropy field increases from $H_o = 25.4$ kOe (0% Pt) to 34.5 kOe (4.5% Pt) but this increase is insufficient to explain the observed increase in coercivity. The ratio H_c/H_o increases from 0.185 for 0% Pt to 0.362 for 4.5% Pt. Both ratios, especially the second one, are large and indicate a very effective pinning mechanism. The increase due to Pt substitution indicates substantial structural inhomogeneities, which is consistent with our finding that the Pt enhances deviations from the perfect NiAs structures and also produces discontinuities on the film surface. Details of the pinning mechanisms are not known at present but the domain wall energy $\gamma = 4(AK_1)^{1/2}$ strongly depends on the interatomic exchange $A \sim z J$, so that nanoscale regions with strongly reduced exchange *J* and/or z are effective pinning centers.

Besides investigating structural and magnetic properties, we have studied the galvanomagnetic properties of Mn55−*x*Pt*x*Bi45 thin films. We have carried out Hall measurement on these samples using the van der Pauw method. The samples exhibit a large extraordinary Hall effect. Hall resistivity $\rho_{xy}(H)$ loops for samples with platinum concentration of 0, 1.5, and 3 at. % are essentially identical to their $M(H)$ hysteresis loops, as shown in Fig. [4.](#page-3-15) However, $\rho_{xy}(H)$ for the sample with 4.5 at. % Pt shows a quadratic dependence on magnetic field, indicating that the ordinary magnetoresistance starts dominating as the Pt concentration increases, as shown in the left inset in Fig. [4.](#page-3-15) We have determined the normal and anomalous Hall coefficients R_o and R_s by fitting $\rho_{xy} = R_oB + 4\pi R_sM_s$ to the high field $\rho_{xy}(H)$ data, where B is the magnetic induction and M_s is the saturation magnetization.^{[20](#page-3-16)} For all the samples, the R_s values are about one order of magnitude larger than R_o values, which is consistent with past research. 21 As shown in the right inset of Fig. [4,](#page-3-15) $\overrightarrow{R_s}$ increases from 1.26×10^{-10} to 1.49 $\times 10^{-10}$ Ω cm/G and *R_o* decreases from 5.7 × 10⁻¹² to 1.0 $\times 10^{-13}$ Ω cm/G as the Pt concentration increases from 0 to 3 at. %. We could not precisely determine the values of *Ro* and R_s for the sample with 4.5% Pt due to the quadratic dependence of ρ_{xy} on H. The increase in R_s and decrease in R_o is consistent with the increase in resistivity of the samples due to Pt substitution. 21

IV. CONCLUSIONS

We have investigated the structural, magnetic and magneto-transport properties of $Mn_{55-x}Pt_xBi_{45}$ ($x=0, 1.5, 3,$ and 4.5) thin films prepared by e-beam multilayer deposition and annealing. We have found that the magnetic properties of MnBi are very sensitive to the substitution of a third element such as Pt. Saturation magnetization and coercivity of the samples show a systematic change with the Pt concentration. The substantial decrease in magnetization and increase in the coercivity of the Pt-alloyed samples can be attributed to the defect structure with strong pining centers. The increase in the resistivity of the samples due to platinum substitution causes an increase in the extraordinary Hall coefficient and decrease in the ordinary Hall coefficient.

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